SIEMENS

Data sheet

3RF2340-1AA14



Solid-state contactor 1-phase 3RF2 AC 51 / 40 A / 40 $^\circ\text{C}$ 48-460 V / 24 V AC/DC screw terminal

product brand name	SIRIUS			
product designation	solid-state contactor			
design of the product	single-phase			
product type designation	3RF23			
manufacturer's article number				
 _1 of the accessories that can be ordered 	<u>3RF2900-3PA88</u>			
 _3 of the accessories that can be ordered 	<u>3RF2900-0EA18</u>			
 _4 of the accessories that can be ordered 	<u>3RF2950-0GA16</u>			
product designation				
 _1 of the accessories that can be ordered 	terminal cover			
 _3 of the accessories that can be ordered 	converter			
 _4 of the accessories that can be ordered 	load monitoring			
General technical data				
product function	zero-point switching			
power loss [W] for rated value of the current				
 at AC in hot operating state 	44 W			
 at AC in hot operating state per pole 	44 W			
 without load current share typical 	0.5 W			
insulation voltage rated value	600 V			
degree of pollution	3			
type of voltage				
 of the operating voltage 	AC			
 of the control supply voltage 	AC/DC			
surge voltage resistance of main circuit rated value	6 kV			
protection class IP	IP20			
protection class IP on the front according to IEC 60529	IP20			
shock resistance according to IEC 60068-2-27	15g / 11 ms			
vibration resistance according to IEC 60068-2-6	2g			
reference code according to IEC 81346-2	Q			
Substance Prohibitance (Date)	05/28/2009			
SVHC substance name	Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8 Dibutylbis(pentane-2,4-dionato-O,O')tin - 22673-19-4			
Weight	0.453 kg			
Main circuit				
number of poles for main current circuit	1			
number of NO contacts for main contacts	1			
number of NC contacts for main contacts	0			
type of voltage of the operating voltage	AC			
operating voltage				
• at AC				

— at 50 Hz rated value	48 460 V		
— at 60 Hz rated value	48 460 V		
operating frequency rated value	50 60 Hz		
operating range relative to the operating voltage at AC			
• at 50 Hz	40 506 V		
• at 60 Hz	40 506 V		
operational current			
 at AC-51 rated value 	40 A		
 at AC-51 according to IEC 60947-4-3 	33 A		
according to UL 508 rated value	36 A		
operational current minimum	500 mA		
rate of voltage rise at the thyristor for main contacts maximum permissible	1 000 V/µs		
blocking voltage at the thyristor for main contacts maximum permissible	1 200 V		
reverse current of the thyristor	10 mA		
derating temperature	40 °C		
surge current resistance rated value	1 200 A		
l2t value maximum	7 200 A ² ·s		
Control circuit/ Control			
type of voltage of the control supply voltage	AC/DC		
control supply voltage 1 at AC			
• at 50 Hz	24 24 V		
at 60 Hz	24 24 V		
control supply voltage frequency 1 rated value 	50 Hz		
• 2 rated value	60 Hz		
control supply voltage 1 at DC rated value maximum	30 V		
permissible			
control supply voltage 1 at DC	15 24 V		
control supply voltage at AC			
 at 50 Hz full-scale value for signal<0> recognition 	5 V		
at 60 Hz full-scale value for signal<0> recognition	5 V		
control supply voltage			
at AC initial value for signal <1> detection			
 at DC initial value for signal <1> detection at DC full-scale value for signal<0> recognition 	15 V 5 V		
symmetrical line frequency tolerance	5 Hz		
control current at minimum control supply voltage	5112		
• at AC	2 mA		
control current at AC rated value	15 mA		
control current at DC rated value	20 mA		
ON-delay time	1 ms; additionally max. one half-wave		
OFF-delay time	15 ms; additionally max. one half-wave		
Auxiliary circuit			
type of switching contact	normally open contact (NO)		
number of NC contacts for auxiliary contacts	0		
number of NO contacts for auxiliary contacts	0		
number of CO contacts for auxiliary contacts	0		
Installation/ mounting/ dimensions			
fastening method side-by-side mounting	Yes		
fastening method	screw fixing and snap-on mounting on standard mounting rail 35 mm according to IEC 60715		
design of the thread of the screw for securing the equipment	M4		
height	100 mm		
width	67 mm		
depth	141 mm		
Connections/ Terminals			
product component removable terminal for auxiliary and control circuit	Yes		
type of electrical connection			

 for main current circuit 			
a for auxiliany and control sizewit	screw-type terminals		
for auxiliary and control circuit	screw-type terminals		
type of connectable conductor cross-sections			
for main contacts	212 (4 - 2 - 2 - 2 - 2 - 2 - 2 - 2 - 2 - 2 -		
— solid	2x (1.5 2.5 mm ²), 2x (2.5 6 mm ²)		
— finely stranded with core end processing	2x (1 2.5 mm ²), 2x (2.5 6 mm ²), 1x 10 mm ²		
for AWG cables for main contacts	2x (14 10)		
connectable conductor cross-section for main contacts	4.5 0		
solid or stranded	1.5 6 mm ²		
finely stranded with core end processing	1 10 mm²		
type of connectable conductor cross-sections			
 for auxiliary and control contacts — solid 	$1 \times (0.5 - 2.5 \text{ mm}^2) 2 \times (0.5 - 1.0 \text{ mm}^2)$		
 — finely stranded with core end processing 	1x (0.5 2.5 mm ²), 2x (0.5 1.0 mm ²)		
 — finely stranded with core end processing — finely stranded without core end processing 	1x (0.5 2.5 mm ²), 2x (0.5 1.0 mm ²)		
 for AWG cables for auxiliary and control contacts 	1x (0.5 2.5 mm ²), 2x (0.5 1.0 mm ²)		
AWG number as coded connectable conductor cross section for	1x (AWG 20 12) 10 14		
main contacts	10 14		
tightening torque			
• for main contacts with screw-type terminals	2 2.5 N·m		
 for auxiliary and control contacts with screw-type terminals 	0.5 0.6 N·m		
tightening torque [lbf·in]			
 for main contacts with screw-type terminals 	18 22 lbf·in		
 for auxiliary and control contacts with screw-type terminals 	4.5 5.3 lbf·in		
design of the thread of the connection screw			
for main contacts	M4		
 of the auxiliary and control contacts 	M3		
stripped length of the cable			
for main contacts	7 mm		
 for auxiliary and control contacts 	7 mm		
Electrical Safety			
protection class IP on the front according to IEC 60529	IP20		
touch protection on the front according to IEC 60529	finger-safe, for vertical contact from the front		
Ambient conditions	4 000		
installation altitude at height above sea level maximum	1 000 m		
ambient temperature			
during operation	-25 +60 °C		
during storage	-25 +80 °C		
during storage Electromagnetic compatibility			
during storage Electromagnetic compatibility conducted interference	-55 +80 °C		
• during storage Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4	-55 +80 °C 2 kV / 5 kHz behavior criterion 2		
• during storage Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2		
• during storage Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2		
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• during storage Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2		
• during storage Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1		
• during storage Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	-55 +80 °C 2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment		
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cylindrical design 2	2 x 58 mm usable				
manufacturer's article n	umber of the gG fuse				
• at NH design usable		3NA6812; These fuses have a smaller rated current than the semiconductor relays			
• at cylindrical design 14 x 51 mm usable		<u>3NW6112-1: These fuses have a smaller rated current than the semiconductor</u> relays			
• at cylindrical design 22 x 58 mm usable		<u>3NW6212-1: These fuses have a smaller rated current than the semiconductor</u> relays			
manufacturer's article n	umber				
of DIAZED fuse usable		5SB4111: These fuses have a smaller rated current than the semiconductor relays			
 of NEOZED fuse 	usable		5SE2335: These fuses har relays	ave a smaller rated current than	n the semiconductor
Approvals Certificates					
General Product App	roval				EMV
<u>Confirmation</u>	UK CA	CE EG-Konf.		EHC	RCM
Test Certificates		other		Railway	Environment
<u>Type Test Certific-</u> ates/Test Report	<u>Special Test Certific-</u> <u>ate</u>	Confirmation	UDE VDE	<u>Special Test Certific-</u> <u>ate</u>	Environmental Con- firmations

Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2340-1AA14

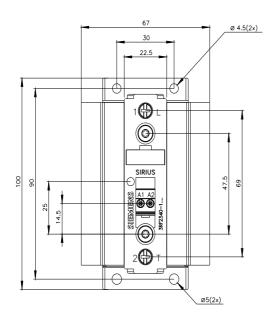
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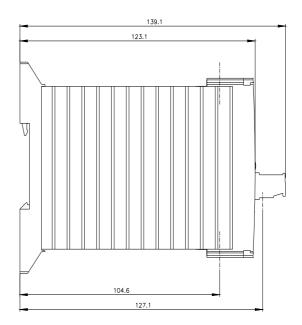
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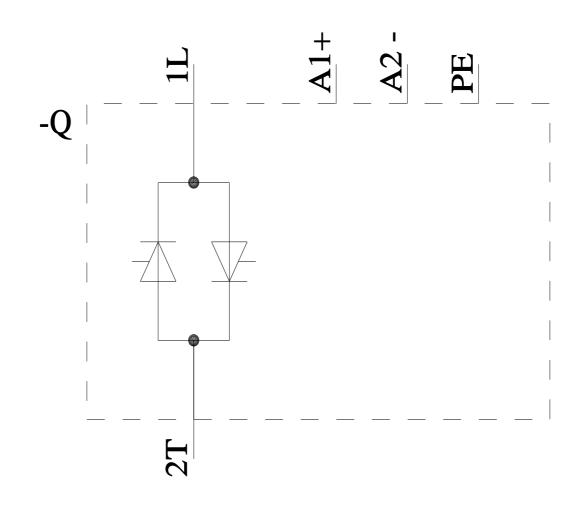
Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

https://support.industry.siemens.com/cs/ww/en/ps/3RF2340-1AA14

Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...) http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3RF2340-1AA14&lang=en







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